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View Online at https://aerobasegroup.com/nsn/5962-01-151-1328 **Body Length:** 1.290 inches **Body Width:** 0.600 inches **Body Height:** 0.205 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -40.0/+85.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **End Application:** An/ugc-12 (v) teletypewriter set **Features Provided:** Monolithic and programmable and erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 6.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 19397-st67411a drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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